

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	IS&R	L1	5861	(257/79,94,98,99).CCLS.	US-PGPUB; USPAT; EPO; DERWENT	2007/05/23 15:17
2	BRS	L2	4748	1 and semiconductor	US-PGPUB; USPAT; EPO; DERWENT	2007/05/23 15:18
3	BRS	L3	662	2 and semiconductor near5 (hole opening "through hole" aperture)	US-PGPUB; USPAT; EPO; DERWENT	2007/05/23 15:24
4	BRS	L4	22	3 and (hole opening "through hole" aperture) near5 wavelength	US-PGPUB; USPAT; EPO; DERWENT	2007/05/23 15:24
5	BRS	L5	6	4 and @ad<"20020128"	US-PGPUB; USPAT; EPO; DERWENT	2007/05/23 15:24
6	BRS	L6	52838	("light emitting device" "light emitting diode") and semiconductor	US-PGPUB; USPAT; JPO; DERWENT	2007/05/23 15:23
7	BRS	L10	1293	6 and semiconductor near5 (holes openings "through holes" apertures)	US-PGPUB; USPAT; EPO; DERWENT	2007/05/23 15:37
8	BRS	L11	23	10 and (holes openings "through holes" apertures) near5 wavelength	US-PGPUB; USPAT; EPO; DERWENT	2007/05/23 15:26
9	BRS	L12	13	11 and @ad<"20020128"	US-PGPUB; USPAT; EPO; DERWENT	2007/05/23 15:38
10	BRS	L15	15017	6 and (holes openings "through holes" apertures "air holes" "light holes")	US-PGPUB; USPAT; EPO; DERWENT	2007/05/23 15:38
11	BRS	L16	217	15 and (holes openings "through holes" apertures "air holes" "light holes") near5 wavelength	US-PGPUB; USPAT; EPO; DERWENT	2007/05/23 15:38
12	BRS	L17	73	16 and @ad<"20020128"	US-PGPUB; USPAT; EPO; DERWENT	2007/05/23 15:39